

产品规格书

Specifcation of products

产品名称: 整流管模块

产品型号: MDC100A-T03

浙江世菱半导体有限公司

ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

地址: 浙江省 丽水市 莲都区

电话: (0578) 3012571 3615078

传真: (0578) 3611180

邮编: 323000

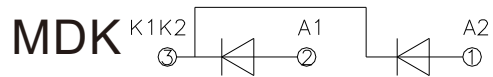
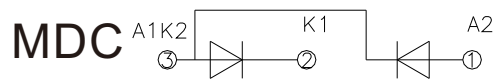
E-mail: smrshiling01@163.com

Http://www.smrshiling.com

拟制	审核	核准
林益龙	曹剑龙	宗瑞

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean for ward current	180° half sine wave 50Hz Single side cooled,T _C =100°C	150			100	A
I _{F(RMS)}	RMS for ward current	Single side cooled,T _C =100°C	150			157	A
V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms V _{RSM} = V _{DRM} &V _{RRM} +200V	150	600		2200	V
I _{RRM}	Repetitive peak current	at V _{RRM}	150			8	mA
I _{FSM}	Surge for ward current	10ms half sine wave V _R =0.6V _{RRM}	150			2.60	KA
I ² t	I ² T for fusing coordination					34.4	A ² s*10 ³
V _{FO}	Threshold voltage		150			0.80	V
r _F	Forward slop resistance					1.74	mΩ
V _{FM}	Peak for ward voltage	I _{FM} =300A	25			1.1	V
R _{th(j-c)}	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.350	°C/W
V _{iso}	Isolation voltage	50Hz, RM. S, t=1min,I _{iso} : 1mA (ma x)		2500			V
F _m	Terminal connection torque(M5)					4.0	N.m
	Mounting torque(M6)					5.0	N.m
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight					154	g
Outline							

OUTLINE DR AWING & CIRCUIT DIAGRAM



Rating and Characteristic

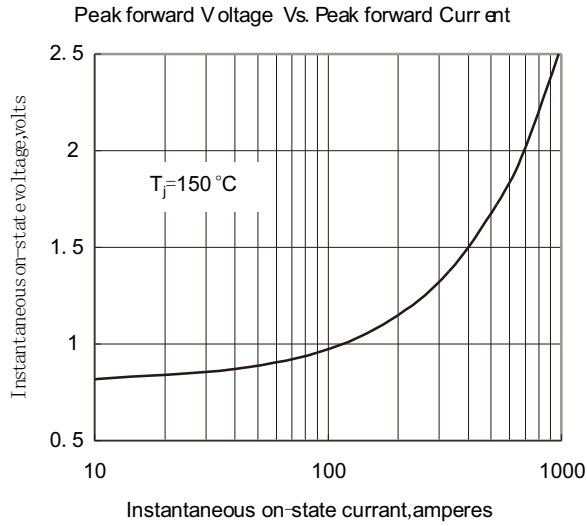


Fig. 1

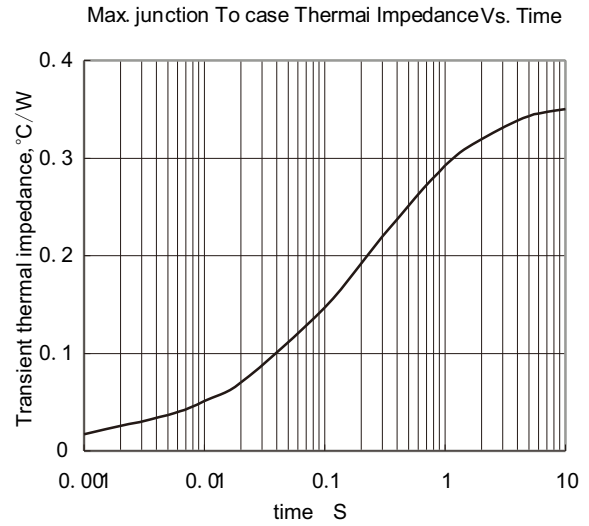


Fig. 2

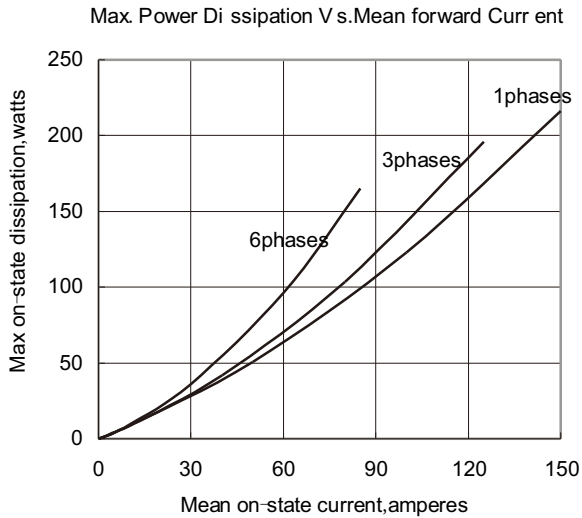


Fig. 3

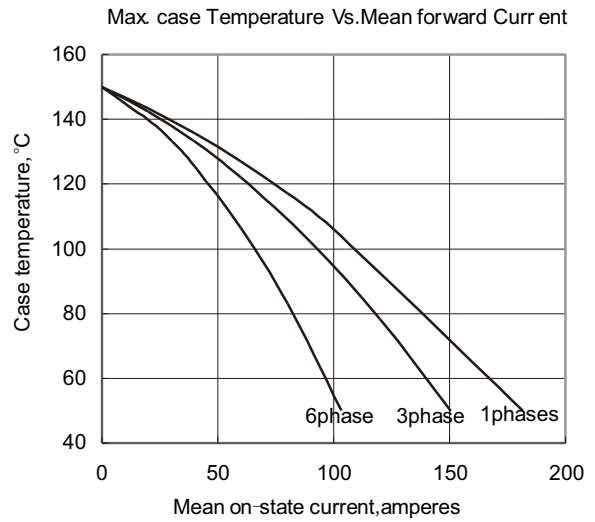


Fig. 4

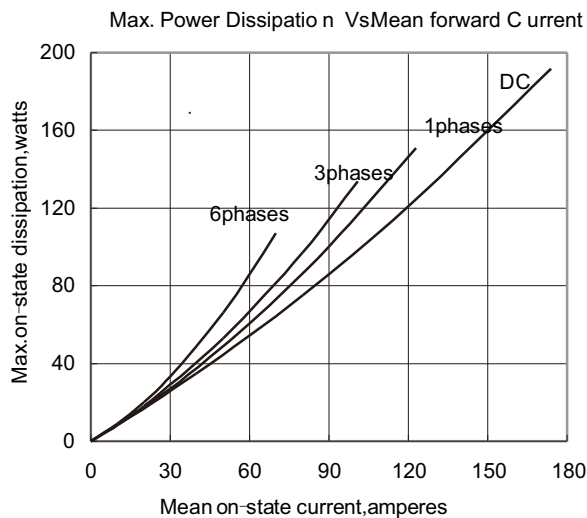


Fig. 5

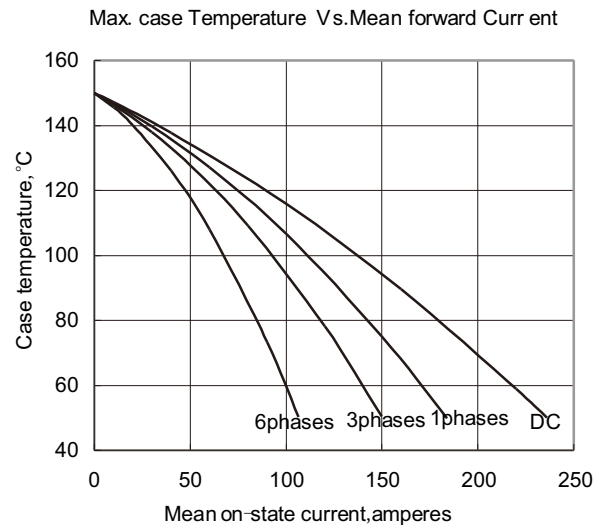


Fig. 6

Outside Dimension

